Preferred Device

勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-54151736 胜特力电子(深圳) 86-755-83298787

Http://www.100y.com.tw



Monolithic Dual Switching Diode Common Anode

Features

• Pb-Free Packages are Available

MAXIMUM RATINGS (EACH DIODE)

Rating	Symbol	Value	Unit
Reverse Voltage	V_{R}	70	Vdc
Forward Current	I _F	200	mAdc
Peak Forward Surge Current	I _{FM(surge)}	500	mAdc
Non-Repetitive Peak Forward Current t = 1 μs (Note 3)	I _{FSM}	41.10	A

THERMAL CHARACTERISTICS

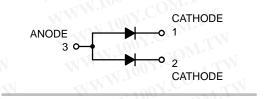
Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1) T _A = 25°C Derate above 25°C	P _D	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{ heta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) T _A = 25°C Derate above 25°C	P _D	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{ heta JA}$	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

- 1. $FR-5 = 1.0 \times 0.75 \times 0.062$ in.
- 2. Alumina = $0.4 \times 0.3 \times 0.024$ in. 99.5% alumina.
- 3. Square Wave; T_i = 25°C.

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SOT-23 (TO-236) CASE 318 STYLE 12

MARKING DIAGRAM



A1 = Device Code

M = Date Code*

Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]	
BAW56LT1	SOT-23	3000 / Tape & Reel	
BAW56LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel	
BAW56LT3	SOT-23	10,000 / Tape & Reel	
BAW56LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel	

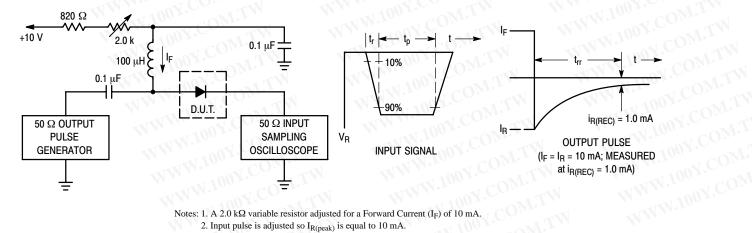
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

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VWW.100Y.COM.TW **ELECTRICAL CHARACTERISTICS** (T_A = 25°C unless otherwise noted) (Each Diode)

OFF CHARACTERISTICS	1007	- 11			
Reverse Breakdown Voltage	(I _(BR) = 100 μAdc)	$V_{(BR)}$	70	IM -	Vdo
Reverse Voltage Leakage Current	$(V_R = 25 \text{ Vdc}, T_J = 150^{\circ}\text{C})$ $(V_R = 70 \text{ Vdc})$ $(V_R = 70 \text{ Vdc}, T_J = 150^{\circ}\text{C})$	I _R	00X-CO	30 2.5 50	μAd
Diode Capacitance (V _R = 0, f = 1.0 MHz)	WWW.IOOY.COM.TW	C _D	.1007.C	2.0	pF
Forward Voltage	$(I_F = 1.0 \text{ mAdc})$ $(I_F = 10 \text{ mAdc})$ $(I_F = 50 \text{ mAdc})$ $(I_F = 150 \text{ mAdc})$	VF	M.100, M.700, M.100,	715 855 1000 1250	mVc
Reverse Recovery Time (I _F = I _R = 10 mAdc, I _{R(REC)} = 1.0 mAdc) (Figure 1) $R_L = 100 \Omega$		t _{rr}	11/1/10	6.0	ns



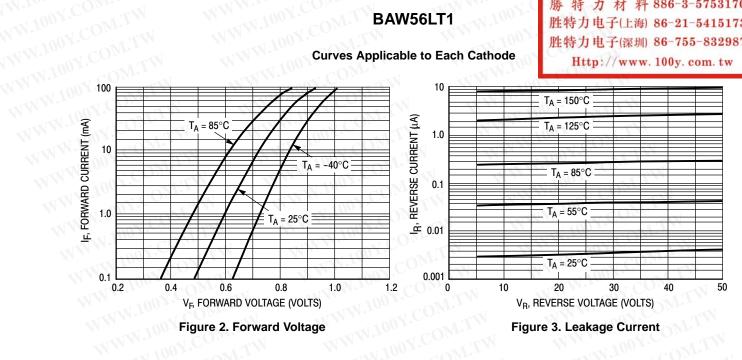
Notes: 1. A 2.0 k Ω variable resistor adjusted for a Forward Current (IF) of 10 mA.

- 2. Input pulse is adjusted so I_{R(peak)} is equal to 10 mA.
- 3. $t_p \gg t_{rr}$

Figure 1. Recovery Time Equivalent Test Circuit

WWW.100Y.COM.TW **Curves Applicable to Each Cathode**

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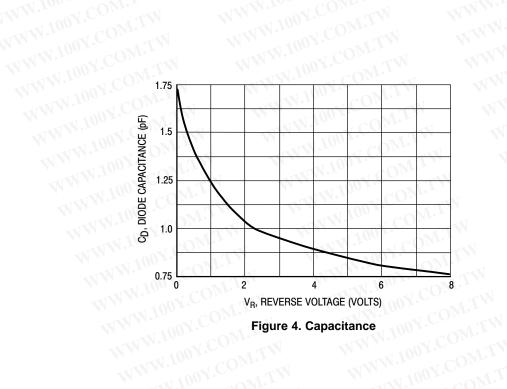


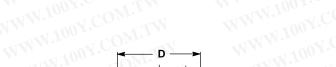
Figure 4. Capacitance WWW.100Y.COM.TW

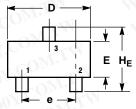
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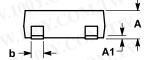
PACKAGE DIMENSIONS

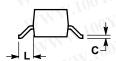
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SOT-23-3 (TO-236) CASE 318-08 ISSUE AL









NOTES:

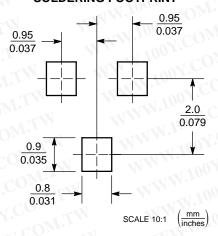
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL. 318-01 THRU -07 AND -09 OBSOLETE, NEW
- STANDARD 318-08

17	М	MILLIMETERS INCHES			7.	
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104

STYLE 12:

PIN 1. CATHODE CATHODE 3. ANODE

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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